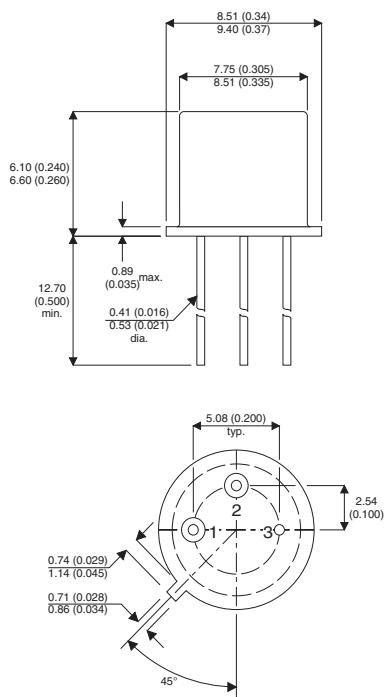


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MECHANICAL DATA

Dimensions in mm (inches)



**Underside View
TO39 PACKAGE (TO-205AD)**

SILICON NPN PLANAR TRANSISTOR

FEATURES

- $V_{CBO} = 120V$
- $V_{CEO} = 120V$
- $I_C = 1.0A$

DESCRIPTION

General Purpose NPN Transistor in a Hermetic TO39 Package

Pin 1 = Emitter Pin 2 = Base Pin 3 = Collector

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^\circ C$ unless otherwise stated)

V_{CBO}	Collector – Base Voltage (open emitter)	120V
V_{CEO}	Collector – Emitter Voltage (open base)	120V
I_C	Collector Current (d.c.)	1.0A
I_{CM}	Collector Current (peak value)	2A
P_{TOT}	Total Device Dissipation @ $T_{amb} \leq 45^\circ C$	0.7W
P_{TOT}	Total Device Dissipation @ $T_C \leq 25^\circ C$	5W
P_{TOT}	Total Device Dissipation @ $T_C \leq 100^\circ C$	2.85W
T_{stg}	Storage Temperature	-65 to 200°C
T_j	Junction Temperature	200°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	35°C / W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	220°C / W

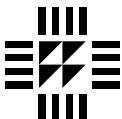
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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)CEO}^*$ Collector – Emitter Breakdown Voltage	$I_C = 10\text{mA}$ $I_B = 0$	120			V
$V_{(BR)CBO}^*$ Collector – Base Breakdown Voltage	$I_C = 100\mu\text{A}$ $I_E = 0$	120			V
$V_{(BR)EBO}^*$ Emitter – Base Breakdown Voltage	$I_E = 100\mu\text{A}$ $I_C = 0$	6			V
I_{CBO} Collector Cut-off Current	$V_{CB} = 60\text{V}$ $I_E = 0$			0.1	μA
	$V_{CB} = 60\text{V}$ $I_E = 0$			50	
	$T_{amb} = 150^\circ\text{C}$				
$V_{CE(sat)}^*$ Collector – Emitter Saturation Voltage	$I_C = 0.1\text{A}$ $I_B = 0.01\text{A}$			0.15	V
	$I_C = 0.5\text{A}$ $I_B = 0.05\text{A}$			0.5	
	$I_C = 1.0\text{A}$ $I_B = 0.15\text{A}$			1.0	
$V_{BE(sat)}^*$ Base – Emitter Saturation Voltage	$I_C = 0.1\text{A}$ $I_B = 0.01\text{A}$			0.9	V
	$I_C = 0.5\text{A}$ $I_B = 0.05\text{A}$			1.1	
	$I_C = 1.0\text{A}$ $I_B = 0.15\text{A}$			1.2	
h_{FE}^* DC Current Gain	$I_C = 0.1\text{A}$ $V_{CE} = 5\text{V}$	40			—
	$I_C = 0.5\text{A}$ $V_{CE} = 5\text{V}$	30			
	$I_C = 1.0\text{A}$ $V_{CE} = 5\text{V}$	15			

t* Pulse test $t_p = 300\mu\text{s}$, $\delta \leq 1.5\%$

DYNAMIC CHARACTERISTICS ($T_{case} = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
f_T Transition Frequency	$I_C = 100\text{mA}$ $V_{CE} = 20\text{V}$ $f = 35\text{MHz}$	50			MHz
C_{obo} Output Capacitance	$V_{CB} = 10\text{V}$ $I_E = 0$ $f = 1.0\text{MHz}$			20	pF
C_{ibo} Input Capacitance	$V_{EB} = 0$ $I_E = 0$ $f = 1.0\text{MHz}$			300	pF
t_{on} Turn-On Time	$I_C = 0.5\text{A}$ $V_{CC} = 20\text{V}$		0.3		μs
t_{off} Turn-Off Time	$I_{B1} = -I_{B2} = 0.05\text{A}$		1.0		

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